U30D60C

Switch mode Dual Ultrafast Power Rectifiers

Designed for use in switching power supplies, inverters and as free-wheeling diodes. These state-of-the-art devices have the following

Features

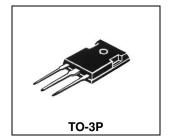
- *Low Reverse Leakage Current
- * Fast Switching for High Efficiency
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage, High Current Capability
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- *Pb free
- *In compliance with EU RoHs directives





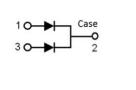
ULTRA FAST RECTIFIERS

30 AMPERES 600 VOLTS



0 → B ← C	→ M ←
<u>↓</u>	T _A
H G	$\begin{array}{c c} \downarrow & \downarrow \\ \downarrow \\$
Ŭ U	<u>↓</u> ↓ ↓

DIM	MILLIMETERS		
ווועו	MIN	MAX	
Α	20.80	21.80	
В	15.38	16.20	
С	1.90	2.70	
D	5.10	6.10	
E	14.50	15.50	
F	11.20	13.20	
G	3.75	4.35	
Н	1.90	2.30	
- 1	2.90	3.30	
J	1.00	1.40	
K	5.26	5.66	
L	19.50	20.50	
M	4.68	5.36	
N	2.30	2.60	
0	3.45	3.85	
Р	0.48	0.72	



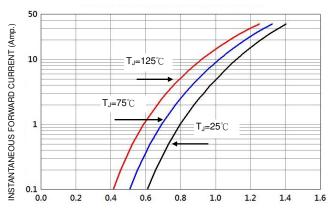
MAXIMUM RATINGS

Characteristic	Symbol	U30D60C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
RMS Reverse Voltage	V _{R(RMS)}	420	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R)	I _{F(AV)}	15 30	Α
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	Іғм	30	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I _{FSM}	250	А
Operating and Storage Junction Temperature Range	$T_J\ , T_stg$	-65 to +150	$^{\circ}\! \mathbb{C}$

ELECTRICAL CHARACTERISTICS

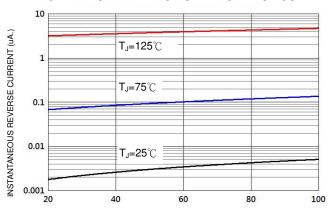
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Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 15 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 15 \text{ Amp } T_C = 125^{\circ}C$)	V _F		1.2 1.0	1.55 	٧
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		0.02 8	10 	uA
Reverse Recovery Time ($I_F = 0.5 \text{ A}$, $I_R = 1.0$, $I_{rr} = 0.25 \text{ A}$)	T _{rr}		33	50	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	СР		100		₽F





FORWARD VOLTAGE (V)

FIG-2 TYPICAL REVERSE CHARACTERISTICS



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

FIG-3 FORWARD CURRENT DERATING CURVE

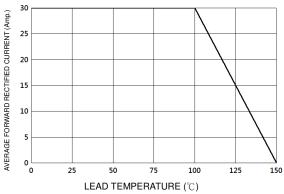


FIG-4TYPICAL JUNCTION CAPACITANCE

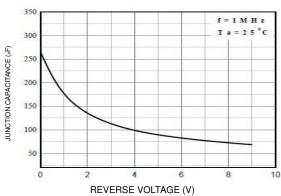
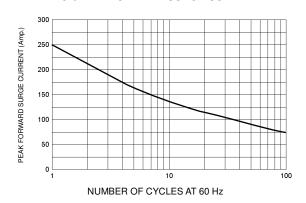
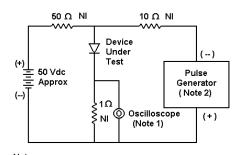
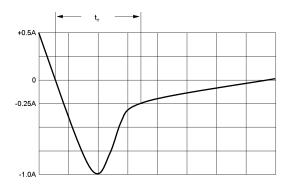


FIG-5PEAK FORWARD SURGE CURRENT





Notes: 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram